

L Numb r	Hits	S arch T xt	DB	Time stamp
-	1560	st r o\$lithography	USPAT; US-P PUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 13:45
-	285	stereo\$lithography and (resist or photo\$resist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 13:45
-	22	(stereo\$lithography and (resist or photo\$resist)) and (laser with (dose or intensity))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 13:46
-	87	((resist or photo\$resist) with (multi\$layer or (multiple adj layers))) and (laser with (dose or intensity))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 12:24
-	3613	stereo\$lithography or sla! or slg!	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 13:45
-	381	(stereo\$lithography or sla! or slg!) and (resist or photo\$resist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 13:45
-	25	((stereo\$lithography or sla! or slg!) and (resist or photo\$resist)) and (laser with (dose or intensity))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 13:57
-	4072	264.clas. and (resist or photoresist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 14:14
-	72	(264.clas. and (resist or photoresist)) and (laser with (dose or intensity))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 14:14
-	385	(250/492.22).CCLS.	USPAT; US-PGPUB	2003/07/01 14:13
-	270	((250/492.22).CCLS.) and (resist or ph t resist)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 14:14

-	22	(((250/492.22).CCLS.) and (resist r ph t r sist)) and (laser with (d se r int nsity))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 14:20
-	15	(((250/492.22).CCLS.) and (resist r ph t r sist)) and (multilay r r (multipl adj layer))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 14:23
-	6	((250/492.22).CCLS.) and (3-d or (three near dimens\$4))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/07/01 14:24